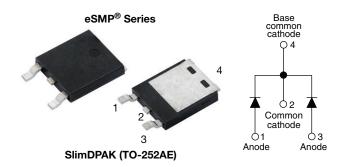
Vishay Semiconductors

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Hyperfast Rectifier, 2 x 3 A FRED Pt[®]



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 3 A			
V _R	200 V			
V _F at I _F	0.75 V			
t _{rr} (typ.)	20 ns			
T _J max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Common cathode			

FEATURES

- Hyperfast recovery time
- 175 °C operating junction temperature
- Low forward voltage drop reduced Q_{rr} and soft recovery
- Low leakage current
- Very low profile typical height of 1.3 mm
- · Ideal for automated placement
- · Polyimide passivation for high reliability standard
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\mathrm{C}$
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage		V _{RRM}		200	V		
Average rectified forward current	per leg		Total device, rated V_R , T_C = 166 °C	3			
Average rectilied forward current	per device	I _{F(AV)}		6	А		
Non-repetitive peak surge current	per leg	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse wave	70			
Operating junction and storage temperatures		T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	200	-	-			
		I _F = 3 A	0.9	1.04				
	VF	I _F = 3 A, T _J = 150 °C	-	0.75	0.82	V		
Forward voltage	٧F	۷F	٧F	I _F = 6 A	-	1	1.2	
		I _F = 6 A, T _J = 150 °C	-	0.85	1.01	1		
Reverse leakage current	1	$V_{R} = V_{R}$ rated	-	-	5			
neverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	80	μA		
Junction capacitance	CT	V _R = 200 V	-	12	-	pF		

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1

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COMPLIANT



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50$	A/ μ s, V _R = 30 V	-	20	-		
Bayaraa raaayary tima	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R$	-	-	25			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	17	-	A	
		T _J = 125 °C	I _F = 3 A dI _F /dt = 200 A/μs V _R = 160 V	-	26	-		
Deals reactions as invent	I _{RRM}	T _J = 25 °C		-	1.8	-		
Peak recovery current I _{RRM}		T _J = 125 °C		-	3.2	-	A	
	0	T _J = 25 °C		-	15	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	41	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾⁽²⁾		-	75	90	°C/W	
Thermal resistance, junction to mount, per leg	R _{thJM} ⁽³⁾		-	3.2	4	°C/W	
Marking device		Case style SlimDPAK (TO-252AE)	6CVH02				

Notes

 $^{(1)}$ The heat generated must be less than thermal conductivity from junction to ambient; $dP_D/dT_J < 1R_{thJA}$

 $^{(2)}$ Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} - junction to ambient

⁽³⁾ Mounted on infinite heatsink

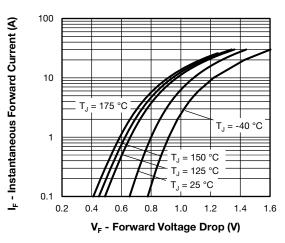


Fig. 1 - Typical Forward Voltage Drop Characteristics

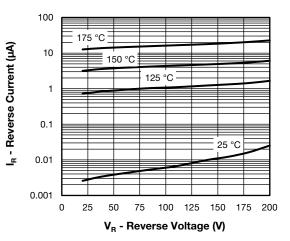


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-6CVH02-M3

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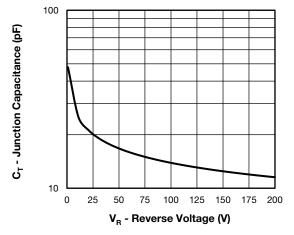


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

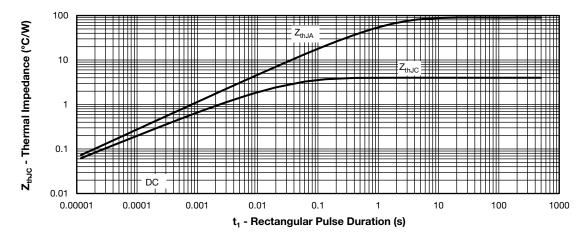
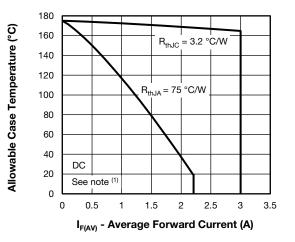
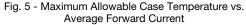


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward power loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \; at \; (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \; (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse power loss} = \mathsf{V}_{\mathsf{R}1} \times \mathsf{I}_{\mathsf{R}} \; (1 - \mathsf{D}); \; \mathsf{I}_{\mathsf{R}} \; at \; \mathsf{V}_{\mathsf{R}1} = \mathsf{rated V}_{\mathsf{R}} \end{array}$

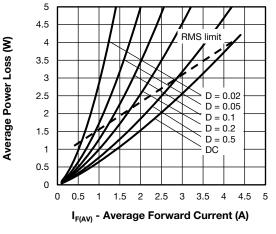


Fig. 6 - Forward Power Loss Characteristics

Revision: 13-Jan-2021

3

Document Number: 96087

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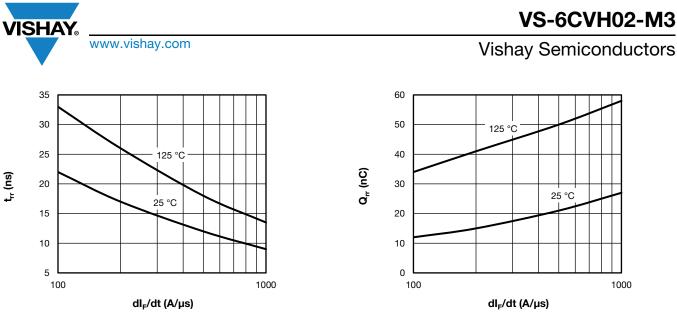


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



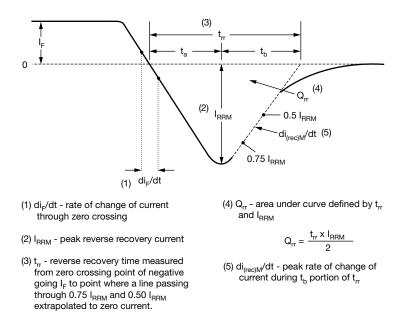


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	6	с	v	н	02	-M3
		Ŭ	Ŭ	•		02	
	1	2	3	4	5	6	(7)
	1	- Visl	nay Sem	nicondu	ctors pro	oduct	
	2	- Cur	rent rati	ng (6 =	6 A)		
	3	- Circ	cuit conf	iguratior	ו:		
		C =	commo	n catho	de		
	4	- V=	SlimDP	AK			
	5		cess typ hyper fa		very		
	6	- Vol	tage coo	le (02 =	200 V)		
	7	- M3	= halog	en-free,	RoHS-0	complia	nt, and t

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-6CVH02-M3/I	4500	4500	13"diameter plastic tape and reel				

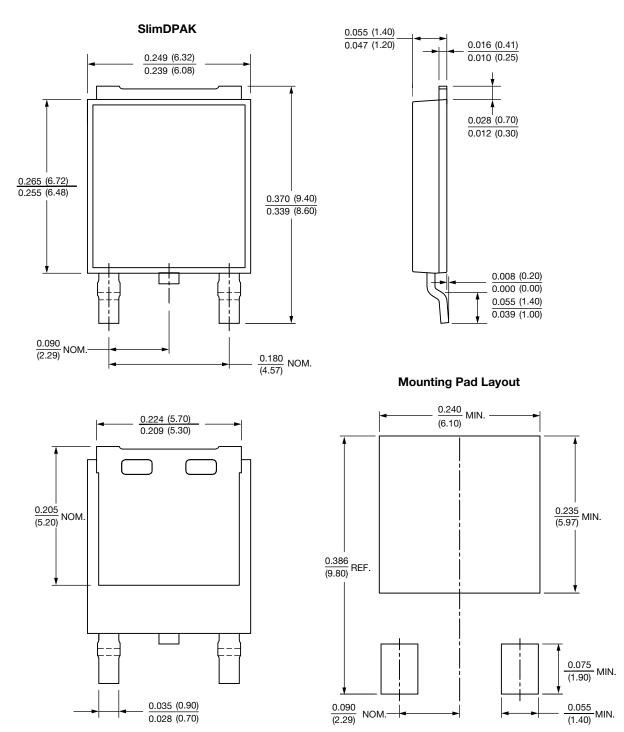
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96081				
Part marking information	www.vishay.com/doc?96085				
Packaging information	www.vishay.com/doc?88869				





SlimDPAK

DIMENSIONS in inches (millimeters)





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